

**HIGH VOLTAGE NPN TRANSISTOR**

**APT27**

**General Description**

The APT27 series are high voltage, high speed switching NPN power transistor specially designed for off-line switch mode power supplies with low output power.

The APT27 series is available in TO-92 package.

**Features**

- High Switching Speed
- High Collector-Emitter Voltage
- Low Cost

**Applications**

- Battery Chargers for Mobile Phone
- Power Supply for DVD/STB

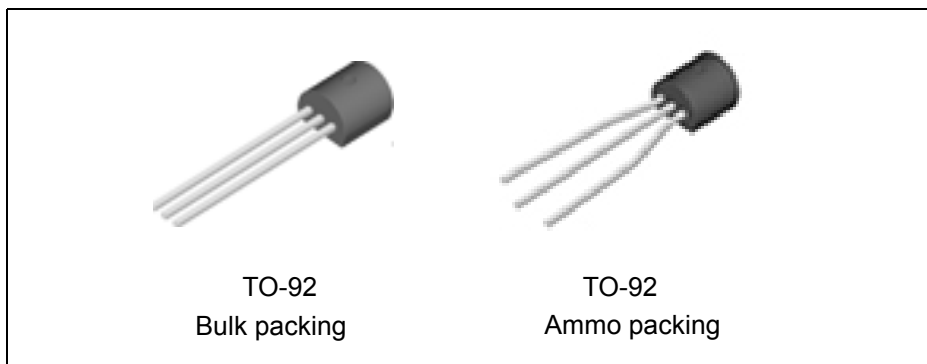


Figure 1. Package Types of APT27

**Pin Configuration**

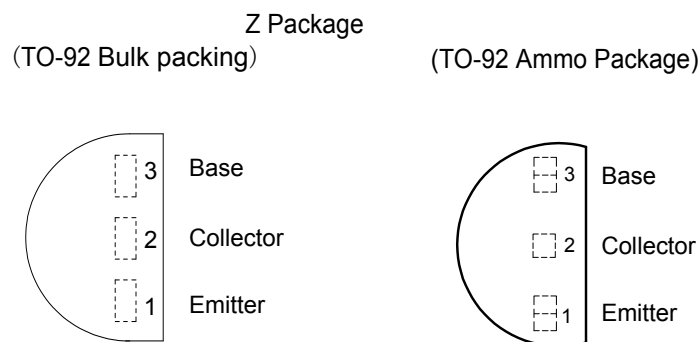


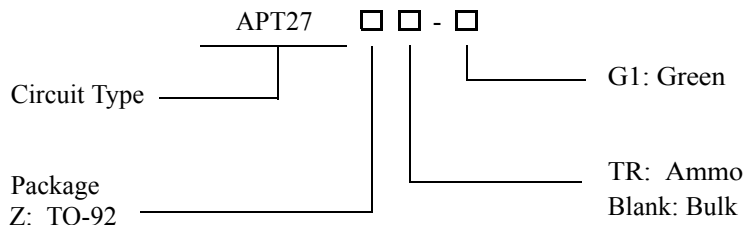
Figure 2. Pin Configurations of APT27 (Top View)



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**Ordering Information**



Package	Part Number	Marking ID	Packing Type
TO-92	APT27Z-G1	APT27Z-G1	Bulk
	APT27ZTR-G1	APT27Z-G1	Ammo

BCD Semiconductor's products, as designated with "G1" suffix in the part number, are RoHS compliant and Green.

**Absolute Maximum Ratings (Note 1)**

Parameter	Symbol	Value	Unit
Collector-Emitter Voltage	$V_{CES}$	700	V
Collector-Emitter Voltage	$V_{CEO}$	450	V
Emitter-Base Voltage	$V_{EBO}$	9	V
Collector Current	$I_C$	0.8	A
Collector Peak Current	$I_{CM}$	1.6	A
Base Current	$I_B$	0.4	A
Base Peak Current	$I_{BM}$	0.8	A
Power Dissipation, $T_A=25^{\circ}C$	$P_{TOT}$	0.8	W
Operating Junction Temperature		150	$^{\circ}C$
Storage Temperature Range		-55 to 150	$^{\circ}C$

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

**HIGH VOLTAGE NPN TRANSISTOR****APT27****Thermal Characteristics**

Parameter	Symbol	Value	Unit
Thermal Resistance (Junction-to-Ambient)	$\theta_{JA}$	156.25	$^{\circ}\text{C}/\text{W}$

**Electrical Characteristics**(  $T_C=25^{\circ}\text{C}$ , unless otherwise specified.)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector Cut-off Current ( $V_{BE}=-1.5\text{V}$ )	$I_{CEV}$	$V_{CE}=700\text{V}$			10	$\mu\text{A}$
Collector-Emitter Sustaining Voltage ( $I_B=0$ )	$V_{CEO}(\text{sus})$	$I_C=0.1\text{mA}$	450			V
Collector-Emitter Saturation Voltage	$V_{CE}(\text{sat})$	$I_C=200\text{mA}$ , $I_B=40\text{mA}$			0.5	V
DC Current Gain	$h_{FE}$	$I_C=100\text{mA}$ , $V_{CE}=10\text{V}$	15	23	40	
		$I_C=300\text{mA}$ , $V_{CE}=10\text{V}$	6	15	30	



Typical Performance Characteristics

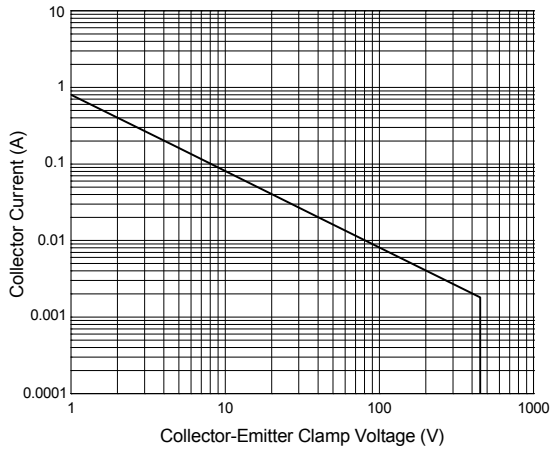


Figure 3. Safe Operating Areas

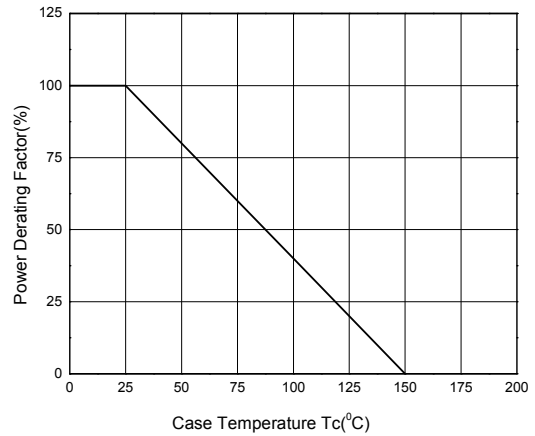


Figure 4. Power Derating Curve

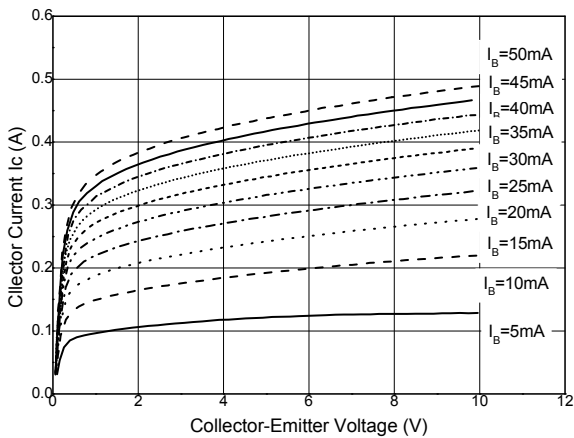


Figure 5. Static Characteristics

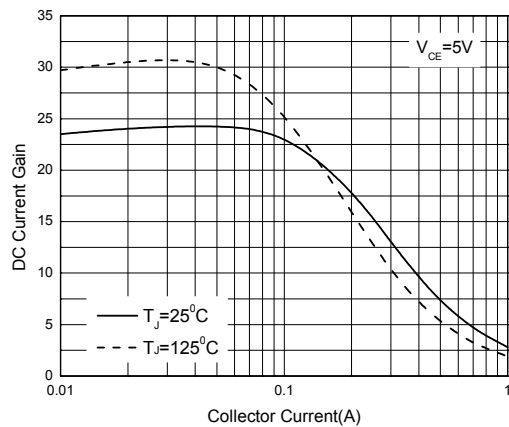


Figure 6. DC Current Gain



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**Typical Performance Characteristics**

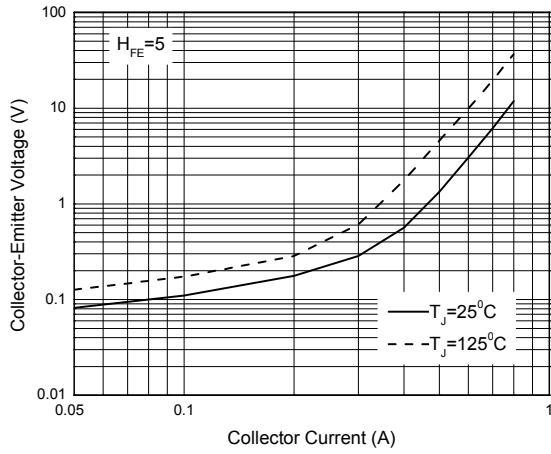


Figure 7. Collector-Emitter Saturation Region

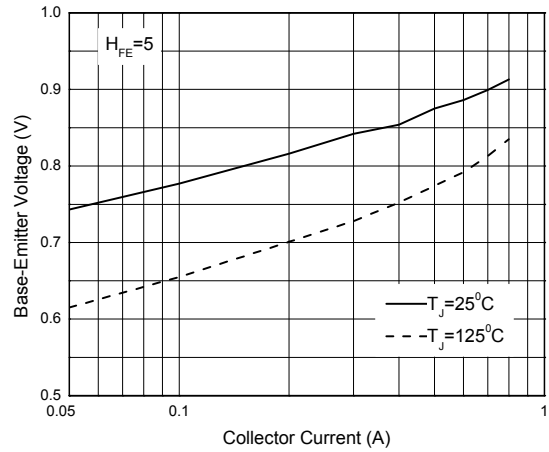


Figure 8. Base-Emitter Saturation Voltage



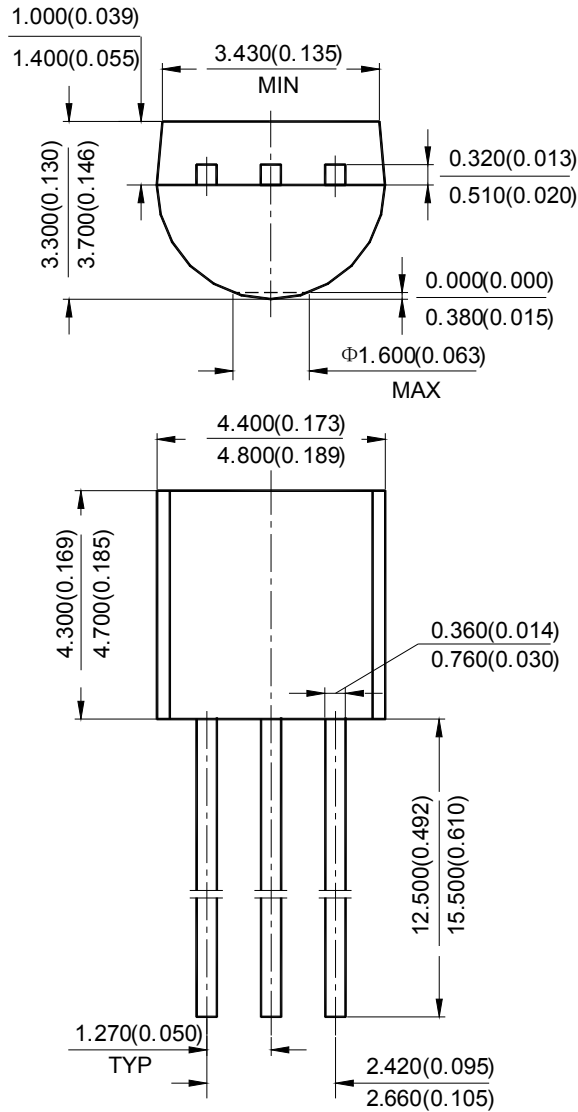
**HIGH VOLTAGE NPN TRANSISTOR**

**APT27**

**Mechanical Dimensions**

**TO-92 (Bulk Packing)**

**Unit: mm(inch)**





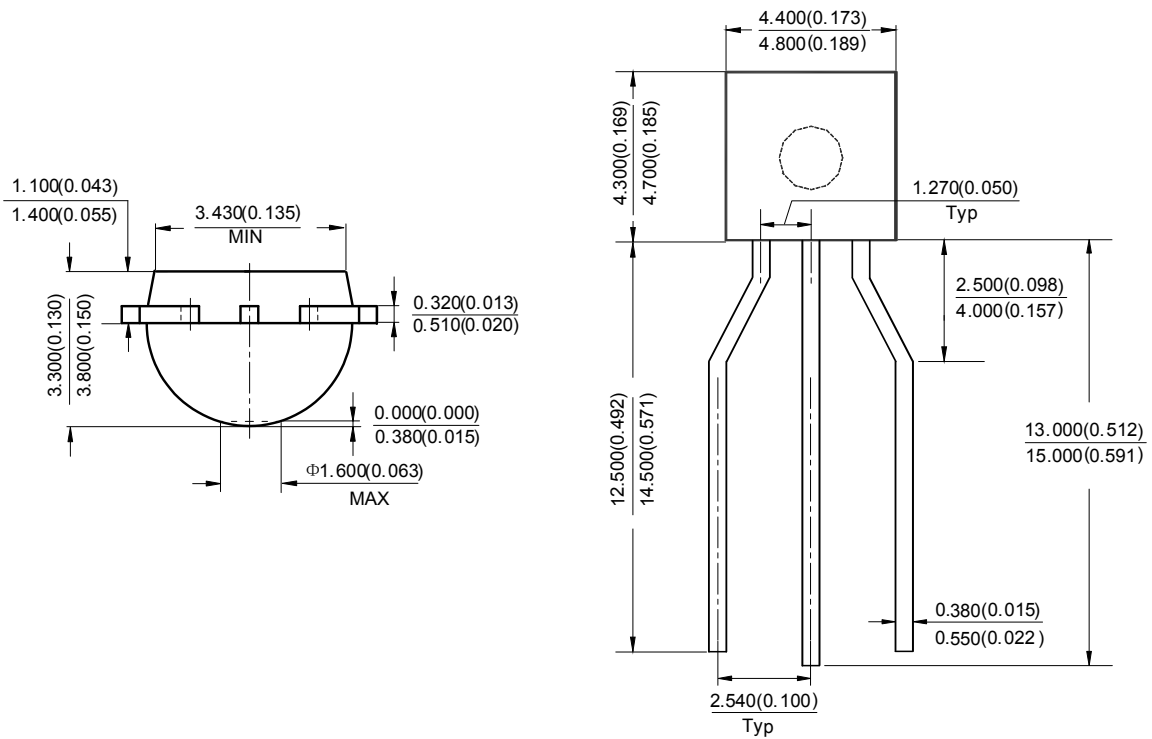
**HIGH VOLTAGE NPN TRANSISTOR**

**APT27**

**Mechanical Dimensions (Continued)**

**TO-92 ( Ammo Packing)**

**Unit: mm(inch)**





## **BCD Semiconductor Manufacturing Limited**

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